

Marcos Guimaraes

List of Publications by Year in descending order

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Version: 2024-02-01

40
papers

2,983
citations

331670
21
h-index

302126
39
g-index

40
all docs

40
docs citations

40
times ranked

4365
citing authors

#	ARTICLE		IF	CITATIONS
1	Unconventional spin Hall effects in nonmagnetic solids. <i>Physical Review Materials</i> , 2022, 6, .		2.4	28
2	The role of device asymmetries and Schottky barriers on the helicity-dependent photoresponse of 2D phototransistors. <i>Npj 2D Materials and Applications</i> , 2021, 5, .		7.9	8
3	Symmetry and control of spin-scattering processes in two-dimensional transition metal dichalcogenides. <i>Physical Review B</i> , 2021, 103, .		3.2	10
4	Enhancing magneto-optic effects in two-dimensional magnets by thin-film interference. <i>AIP Advances</i> , 2021, 11, .		1.3	3
5	Disorder is not always bad for charge-to-spin conversion in WTe ₂ . <i>Matter</i> , 2021, 4, 1440-1441.		10.0	1
6	Transfer of large-scale two-dimensional semiconductors: challenges and developments. <i>2D Materials</i> , 2021, 8, 032001.		4.4	81
7	Interfacial spin-orbit torques and magnetic anisotropy in WSe ₂ /permalloy bilayers. <i>JPhys Materials</i> , 2021, 4, 04LT01.		4.2	5
8	Photoluminescence and charge transfer in the prototypical 2D/3D semiconductor heterostructure MoS ₂ /GaAs. <i>Applied Physics Letters</i> , 2021, 119, .		3.3	10
9	Chiral Spin Spirals at the Surface of the van der Waals Ferromagnet Fe ₃ GeTe ₂ . <i>Nano Letters</i> , 2020, 20, 8563-8568.		9.1	35
10	Nonlinear Analog Spintronics with van der Waals Heterostructures. <i>Physical Review Applied</i> , 2020, 14, .		3.8	2
11	Layer effects on the magnetic textures in magnets with local inversion asymmetry. <i>Physical Review B</i> , 2020, 102, .		3.2	4
12	Spin caloritronics in a CrBr ₃ magnetic van der Waals heterostructure. <i>Physical Review B</i> , 2020, 101, .			
13	Correlated Exciton Fluctuations in a Two-Dimensional Semiconductor on a Metal. <i>Nano Letters</i> , 2020, 20, 4829-4836.		9.1	10
14	Large interfacial spin-orbit torques in layered antiferromagnetic insulator Ni ₃ CrBr ₂ ferromagnet bilayers. <i>Physical Review Materials</i> , 2020, 4, .		2.4	11
15	Spin-Orbit Torques in Transition Metal Dichalcogenide/Ferromagnet Heterostructures. <i>Frontiers in Materials</i> , 2020, 7, .		2.4	21
16	Switching magnetization with a Weyl semimetal. <i>Nature Nanotechnology</i> , 2019, 14, 923-924.		31.5	0
17	MoS ₂ pixel arrays for real-time photoluminescence imaging of redox molecules. <i>Science Advances</i> , 2019, 5, eaat9476.		10.3	19
18	Current-Induced Torques with Dresselhaus Symmetry Due to Resistance Anisotropy in 2D Materials. <i>ACS Nano</i> , 2019, 13, 2599-2605.		14.6	32

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19	Spin-orbit Torques in NbSe ₂ /Permalloy Bilayers. <i>Nano Letters</i> , 2018, 18, 1311-1316.	9.1	89
20	Spin Accumulation and Dynamics in Inversion-Symmetric van der Waals Crystals. <i>Physical Review Letters</i> , 2018, 120, 266801.	7.8	14
21	Spin relaxation 1/f noise in graphene. <i>Physical Review B</i> , 2017, 95, .	3.2	6
22	Thickness dependence of spin-orbit torques generated by $\text{WTe}_2/\text{ferromagnet}$ bilayers. <i>Physical Review B</i> , 2017, 96, .	3.2	104
23	Control of spin-orbit torques through crystal symmetry in WTe ₂ /ferromagnet bilayers. <i>Nature Physics</i> , 2017, 13, 300-305.	16.7	489
24	Atomically Thin Ohmic Edge Contacts Between Two-Dimensional Materials. <i>ACS Nano</i> , 2016, 10, 6392-6399.	14.6	202
25	24 nm spin relaxation length in boron nitride encapsulated bilayer graphene. <i>Physical Review B</i> , 2015, 92, .	3.2	80
26	Graphene spintronics: the European Flagship perspective. <i>2D Materials</i> , 2015, 2, 030202.	4.4	243
27	Fast pick up technique for high quality heterostructures of bilayer graphene and hexagonal boron nitride. <i>Applied Physics Letters</i> , 2014, 105, .	3.3	280
28	Spin transport in graphene nanostructures. <i>Physical Review B</i> , 2014, 90, .	3.2	17
29	Spin-Dependent Quantum Interference in Nonlocal Graphene Spin Valves. <i>Nano Letters</i> , 2014, 14, 2952-2956.	9.1	7
30	Controlling Spin Relaxation in Hexagonal BN-Encapsulated Graphene with a Transverse Electric Field. <i>Physical Review Letters</i> , 2014, 113, 086602.	7.8	182
31	ZnO UV photodetector with controllable quality factor and photosensitivity. <i>AIP Advances</i> , 2013, 3, .	1.3	19
32	Quantum Hall transport as a probe of capacitance profile at graphene edges. <i>Applied Physics Letters</i> , 2013, 102, .	3.3	21
33	From quantum confinement to quantum Hall effect in graphene nanostructures. <i>Physical Review B</i> , 2012, 85, .	3.2	11
34	Contact-induced spin relaxation in Hanle spin precession measurements. <i>Physical Review B</i> , 2012, 86, .	3.2	82
35	Long-distance spin transport in high-mobility graphene on hexagonal boron nitride. <i>Physical Review B</i> , 2012, 86, .	3.2	189
36	Spin Transport in High-Quality Suspended Graphene Devices. <i>Nano Letters</i> , 2012, 12, 3512-3517.	9.1	145

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37	Comparison between charge and spin transport in few-layer graphene. Physical Review B, 2011, 83, .		3.2	76
38	Quantized conductance of a suspended graphene nanoconstriction. Nature Physics, 2011, 7, 697-700.		16.7	143
39	Room-temperature Compression-induced Diamondization of Few-layer Graphene. Advanced Materials, 2011, 23, 3014-3017.		21.0	124
40	Group-theory analysis of electrons and phonons in N -layer graphene systems. Physical Review B, 2009, 79, .		3.2	154